

Vishay Siliconix

RoHS

COMPLIANT HALOGEN

# P-Channel 30-V (D-S) MOSFET

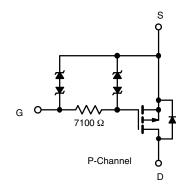
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω <b>)</b>	I <sub>D</sub> (A)		
- 30	0.0085 at V <sub>GS</sub> = - 10 V	- 14		
	0.014 at V <sub>GS</sub> = - 4.5 V	- 11		

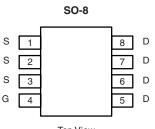
### **FEATURES**

- Halogen-free According to IEC 61249-2-21
  Available
- TrenchFET<sup>®</sup> Power MOSFET
- ESD Protection: 3000 V

### **APPLICATIONS**

- Notebook PC
  - Load Switch
  - Adapter Switch





Top View

Ordering Information: Si4483EDY-T1-E3 (Lead (Pb)-free) Si4483EDY-T1-GE3 (Lead (Pb)-free and Halogen-free)

<b>ABSOLUTE MAXIMUM RATINGS</b> $T_A = 25 \text{ °C}$ , unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	- 30		V	
Gate-Source Voltage		V <sub>GS</sub>	± 25			
	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 14	- 10		
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T <sub>A</sub> = 70 °C		- 11	- 8	•	
Pulsed Drain Current		I <sub>DM</sub>	- 50		A	
Continuous Source Current (Diode Conduction) <sup>a</sup>		ا <sub>S</sub>	- 2.7	- 1.36		
	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	3.0	1.5	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		1.9	0.95	vv	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Marian Incline to Anthian Id	t ≤ 10 s	- R <sub>thJA</sub> R <sub>thJF</sub>	33	42	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		70	85	°C/W
Maximum Junction-to-Foot (Drain)	Steady State		16	21	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \ \mu A$	- 1.0		- 3.0	V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 4.5 V$			± 1	μA		
		$V_{DS} = 0 V, V_{GS} = \pm 25 V$			± 10	mA		
Zero Gate Voltage Drain Current	1	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	- 1		- 1			
	IDSS	$V_{DS}$ = - 30 V, $V_{GS}$ = 0 V, $T_{J}$ = 70 °C			- 10	μΑ		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 V, V_{GS} = -10 V$	- 30			А		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 14 A		0.007	0.0085	Ω		
		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 11 A		0.0115	0.014			
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 14 A		60		S		
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{S} = -2.7 \text{ A}, V_{GS} = 0 \text{ V}$		- 0.74	- 1.1	V		
Dynamic <sup>b</sup>	• •		•		•			
Turn-On Delay Time	t <sub>d(on)</sub>			10	15			
Rise Time	t <sub>r</sub>			20	30			
Turn-Off Delay Time	t <sub>d(off)</sub>			42	65	μs		
Fall Time	t <sub>f</sub>			50	80			

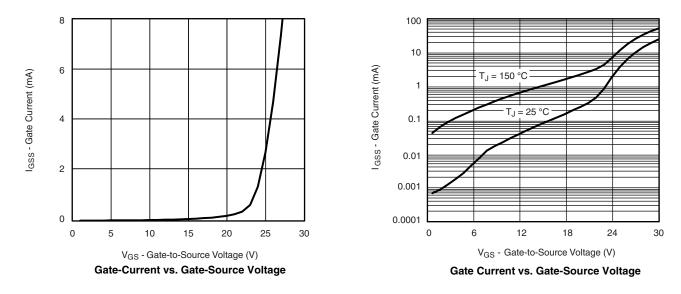
Notes:

a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



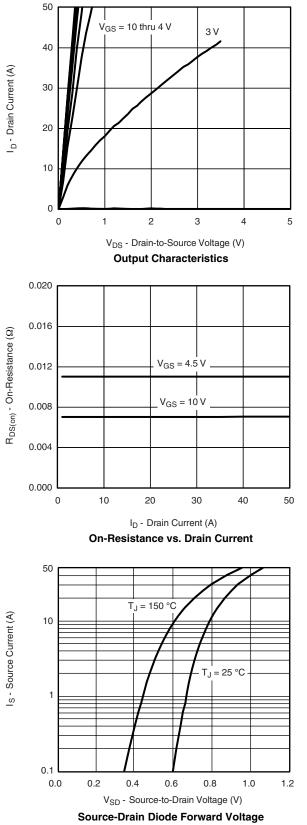
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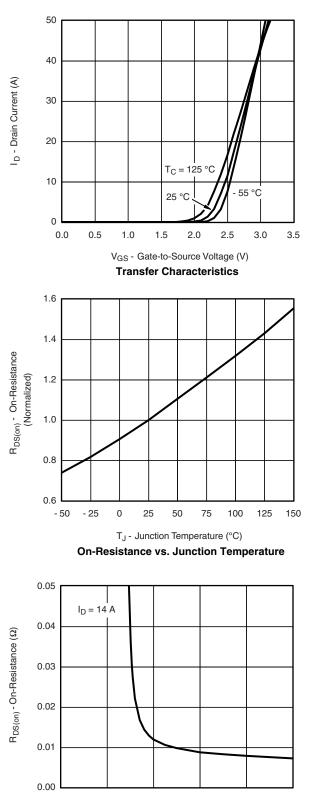


# Si4483EDY

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### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





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V<sub>GS</sub> - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-to-Source Voltage

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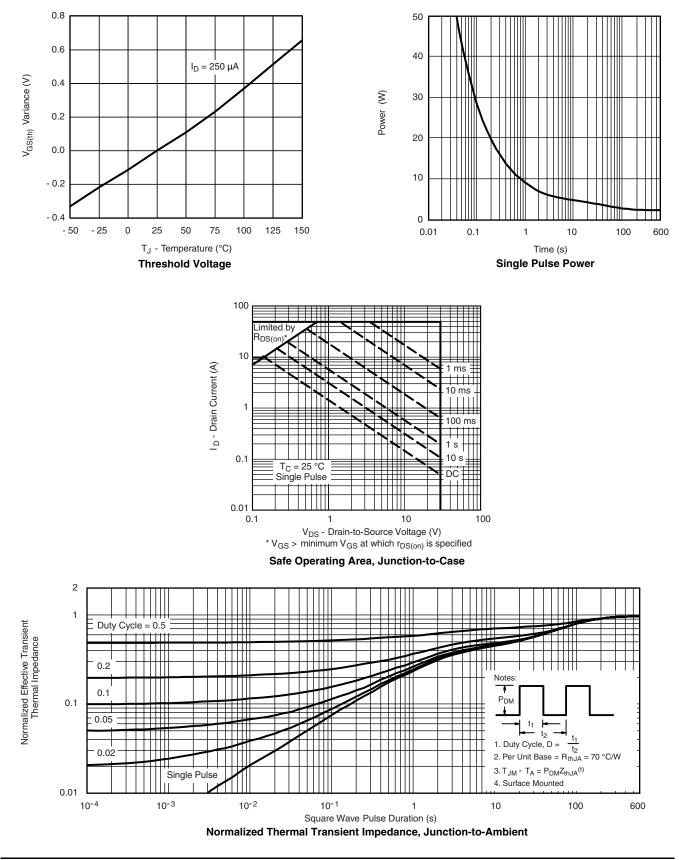
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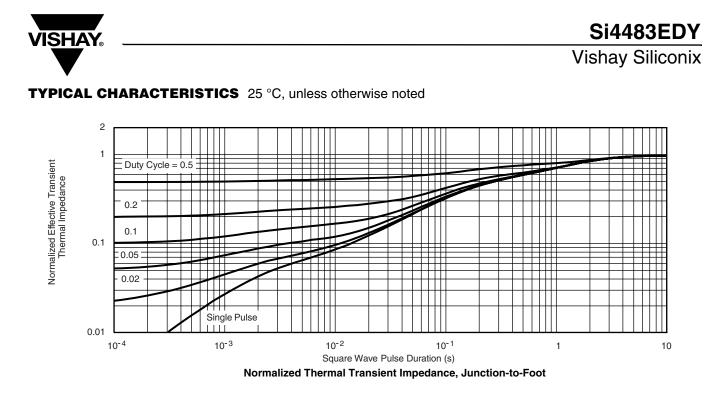
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